TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC74LCX157F,TC74LCX157FN,TC74LCX157FT,TC74LCX157FK

Low Voltage Quad 2-Channel Multiplexer with 5 V Tolerant Inputs and Outputs

The TC74LCX157 is a high-performance CMOS multiplexer. Designed for use in 3.3-V systems, it achieves high-speed operation while maintaining the CMOS low power dissipation.

The device is designed for low-voltage (3.3 V) VCC applications, but it could be used to interface to 5-V supply environment for inputs.

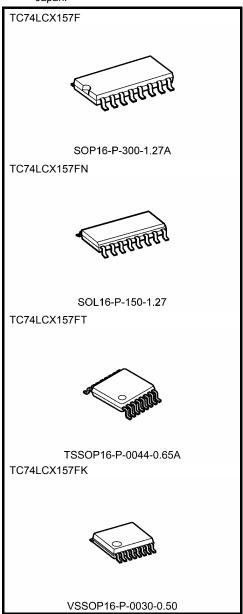
It consists of four 2-input digital multiplexers with common SELECT and \overline{ST} inputs. When the \overline{ST} input is held "H" level, selection of data is inhibited and all the outputs become "L" level. The SELECT decoding determines whether the A or B inputs get routed to their corresponding Y outputs.

All inputs are equipped with protection circuits against static discharge.

Features

- Low-voltage operation: VCC = 2.0 to 3.6 V
- High-speed operation: $t_{pd} = 5.8 \text{ ns (max) (V}_{CC} = 3.0 \text{ to } 3.6 \text{ V)}$
- Ouput current: $|I_{OH}|/I_{OL} = 24 \text{ mA (min)} (V_{CC} = 3.0 \text{ V})$
- Latch-up performance: -500 mA
- Available in JEDEC SOP, JEITA SOP, TSSOP and VSSOP (US)
- · Power-down protection provided on all inputs and outputs
- Pin and function compatible with the 74 series (74AC/VHC/HC/F/ALS/LS etc.) 157 type

Note: xxxFN (JEDEC SOP) is not available in Japan.



Weight

 SOP16-P-300-1.27A
 : 0.18 g (typ.)

 SOL16-P-150-1.27
 : 0.12 g (typ.)

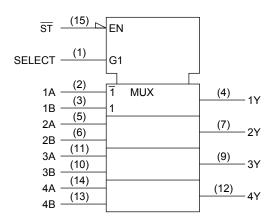
 TSSOP16-P-0044-0.65A
 : 0.06 g (typ.)

 VSSOP16-P-0030-0.50
 : 0.02 g (typ.)

Pin Assignment (top view)

SELECT 16 V_{CC} $\overline{\operatorname{ST}}$ 1A 2 15 1B 4A 3 1Y 13 4B 2A 4Y 5 2B 6 ЗА 2Y 7 10 3B GND 8 3Y

IEC Logic Symbol

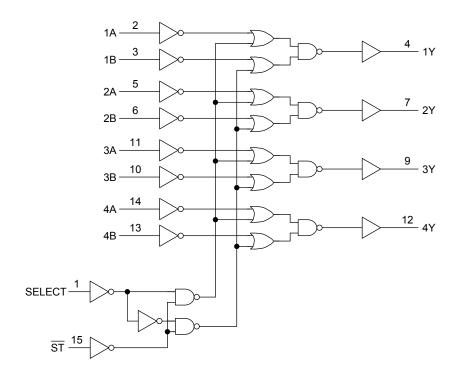


Truth Table

Inputs				Outputs
ST	SELECT A I		В	Υ
Н	Х	Х	Х	L
L	L	L	Х	L
L	L	Н	X	Н
L	Н	Х	L	L
L	Н	Х	Н	Н

X: Don't care

System Diagram



Absolute Maximum Ratings (Note 1)

Characteristics	Symbol	Rating	Unit	
Power supply voltage	V _{CC}	−0.5 to 7.0	V	
DC input voltage	V _{IN}	-0.5 to 7.0	٧	
		-0.5 to 7.0 (Note 2)	V	
DC output voltage	V _{OUT}	-0.5 to V _{CC} + 0.5 (Note 3)		
Input diode current	I _{IK}	-50	mA	
Output diode current	lok	±50 (Note 4)	mA	
DC output current	lout	±50	mA	
Power dissipation	PD	180	mW	
DC V _{CC} /ground current	I _{CC} /I _{GND}	±100	mA	
Storage temperature	T _{stg}	-65 to 150	°C	

Note 1: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 2: $V_{CC} = 0 V$

Note 3: High or low state. IOUT absolute maximum rating must be observed.

Note 4: Vout < GND, Vout > Vcc



Operating Ranges (Note 1)

Characteristics	Characteristics Symbol Rating		Unit
Power supply voltage	V _{CC}	2.0 to 3.6	V
Power supply voltage	vCC	1.5 to 3.6 (Note 2)	V
Input voltage	V _{IN}	0 to 5.5	V
Output voltage	V _{OUT}	0 to 5.5 (Note 3)	V
Output voltage		0 to V _{CC} (Note 4)	V
Output current	I _{OH} /I _{OI}	±24 (Note 5)	mA
Output current	IOH/IOL	±12 (Note 6)	ША
Operating temperature	T _{opr}	-40 to 85	°C
Input rise and fall time	dt/dv	0 to 10 (Note 7)	ns/V

Note 1: The operating ranges must be maintained to ensure the normal operation of the device.

Unused inputs must be tied to either VCC or GND.

Note 2: Data retention only

Note 3: $V_{CC} = 0 V$

Note 4: High or low state

Note 5: $V_{CC} = 3.0 \text{ to } 3.6 \text{ V}$

Note 6: $V_{CC} = 2.7 \text{ to } 3.0 \text{ V}$

Note 7: $V_{IN} = 0.8$ to 2.0 V, $V_{CC} = 3.0$ V

Electrical Characteristics

DC Characteristics ($Ta = -40 \text{ to } 85^{\circ}\text{C}$)

Characteristics		Symbol	Test Condition		V _{CC} (V)	Min	Max	Unit
land to the me	H-level	V _{IH}	_ 		2.7 to 3.6	2.0	_	
Input voltage	L-level	V _{IL}			2.7 to 3.6	_	0.8	V
		Voн	$V_{IN} = V_{IH}$ or V_{IL}	I _{OH} = -100 μA	2.7 to 3.6	V _{CC} -0.2	_	V
	H-level			I _{OH} = -12 mA	2.7	2.2	_	
				I _{OH} = -18 mA	3.0	2.4	_	
Output voltage				I _{OH} = -24 mA	3.0	2.2	_	
	L-level	V _{OL}	V _{IN} = V _{IH} or V _{IL}	I _{OL} = 100 μA	2.7 to 3.6	_	0.2	
				$I_{OL} = 12 \text{ mA}$	2.7	_	0.4	
				$I_{OL} = 16 \text{ mA}$	3.0	_	0.4	
				I _{OL} = 24 mA	3.0	_	0.55	
Input leakage current		I _{IN}	V _{IN} = 0 to 5.5 V		2.7 to 3.6	_	±5.0	μΑ
Power-off leakage current		l _{OFF}	V _{IN} /V _{OUT} = 5.5 V		0	_	10.0	μΑ
Quiescent supply current		Icc	$V_{IN} = V_{CC}$ or GND		2.7 to 3.6	_	10.0	
			V _{IN} = 3.6 to 5.5 V	V _{IN} = 3.6 to 5.5 V		_	±10.0	μА
Increase in Icc per input		Δl _{CC}	V _{IH} = V _{CC} - 0.6 V		2.7 to 3.6	_	500	



AC Characteristics (Ta = -40 to 85°C)

Characteristics	Symbol	Test Condition	V _{CC} (V)	Min	Max	Unit
Propagation delay time	t _{pLH}	Figure 1, Figure 2	2.7	_	6.3	ns
(A, B-Y)	t_{pHL}		3.3 ± 0.3	1.5	5.8	115
Propagation delay time	t _{pLH}	Figure 1, Figure 2	2.7	_	8.0	ne
(SELECT-Y)	t_{pHL}		3.3 ± 0.3	1.5	7.0	ns
Propagation delay time	t _{pLH}	Figure 1, Figure 2	2.7	_	8.0	ns
(ST-Y)	t_{pHL}		3.3 ± 0.3	1.5	7.0	115
Output to output skew	t _{osLH}	(Note)	2.7	_	_	20
	t _{osHL}	(Note)	3.3 ± 0.3	_	1.0	ns

Note: Parameter guaranteed by design.

 $(t_{OSLH} = |t_{pLHm} - t_{pLHn}|, t_{OSHL} = |t_{pHLm} - t_{pHLn}|)$

Dynamic Switching Characteristics

(Ta = 25°C, input: $t_r = t_f = 2.5 \text{ ns}$, $C_L = 50 \text{ pF}$, $R_L = 500 \Omega$)

Characteristics	Symbol	Test Condition	V _{CC} (V)	Тур.	Unit
Quiet output maximum dynamic V _{OL}	V _{OLP}	$V_{IH} = 3.3 \text{ V}, V_{IL} = 0 \text{ V}$	3.3	0.8	V
Quiet output minimum dynamic V _{OL}	V _{OLV}	$V_{IH}=3.3\ V,\ V_{IL}=0\ V$	3.3	8.0	V

Capacitive Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	V _{CC} (V)	Тур.	Unit
Input capacitance	C _{IN}	_	3.3	7	pF
Output capacitance	C _{OUT}	_	0	8	pF
Power dissipation capacitance	C _{PD}	$f_{\text{IN}} = 10 \text{ MHz}$ (Note)	3.3	25	pF

Note: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

 $I_{CC (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}$

AC Test Circuit

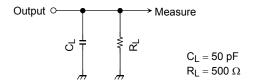


Figure 1

AC Waveform

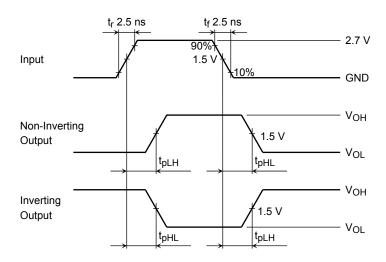
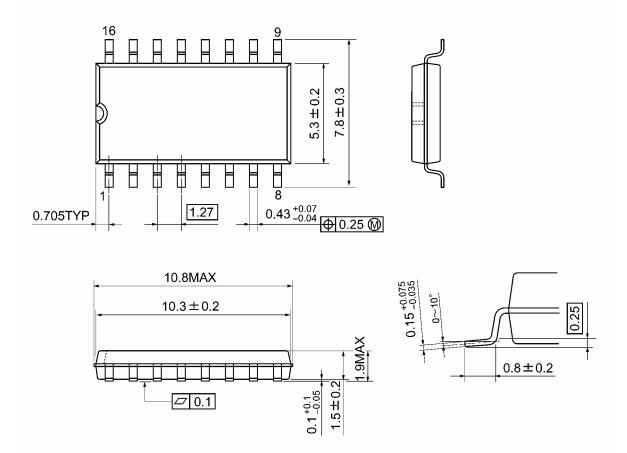


Figure 2 t_{pLH}, t_{pHL}

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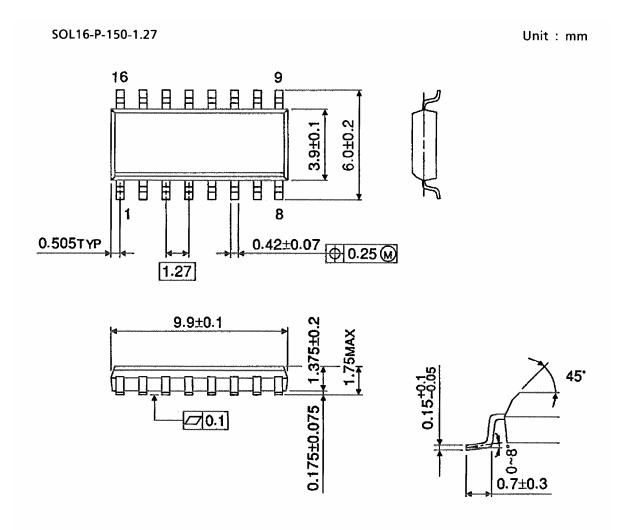
Package Dimensions

SOP16-P-300-1.27A Unit: mm



Weight: 0.18 g (typ.)

Package Dimensions (Note)

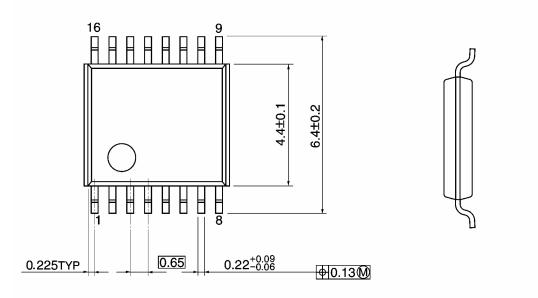


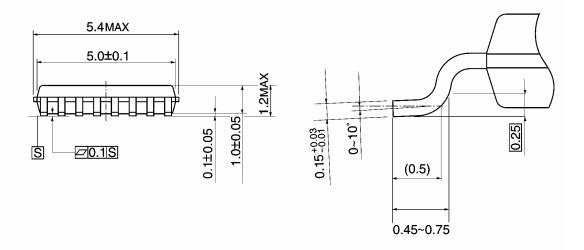
Note: This package is not available in japan.

Weight: 0.12 g (typ.)

Package Dimensions

TSSOP16-P-0044-0.65A Unit: mm

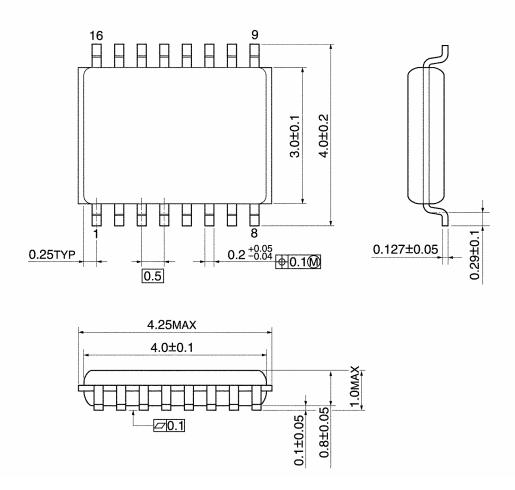




Weight: 0.06 g (typ.)

Package Dimensions

VSSOP16-P-0030-0.50 Unit: mm



Weight: 0.02 g (typ.)

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20070701-EN GENERAL

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